

DA9271.003 23 April 2003

MAS9271

This is preliminary information on a new product under development. Micro Analog Systems reserves the right to make any changes without notice.



- IC FOR 10.00 40.00 MHz PXO
- Low Power
- Wide Supply Voltage Range
- Square Wave Output
- Very High Level of Integration
- Electrically Trimmable
- Very Low Phase Noise
- Low Cost

DESCRIPTION

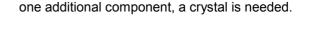
The MAS9271 is an integrated circuit well suited to make initial offset trimming of the crystal in oscillator. The trimming is done by a serial bus and the calibration information is stored in an internal PROM.

Very small size

FEATURES

- Minimum current draw
- Wide operating temperature range
- Phase noise <-130 dBc/Hz at 1 kHz offset
- Square wave output

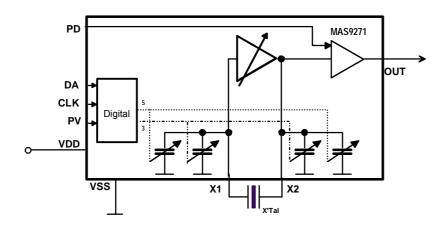
BLOCK DIAGRAM



To build a Precision Crystal Oscillator (PXO) only

APPLICATIONS

- PXO for data terminals
- PXO for telecommunication applications
- PXO for computer application





PIN DESCRIPTION

Pin Description	Symbol	x-coordinate	y-coordinate	Note
Power Supply Voltage	VDD	177	172	
Serial Bus Data Input	DA	435	1015	
Serial Bus Clock Input	CLK	201	1015	
Programming Input	PV	1042	1015	
Tri State	PD	1012	158	-1)
Crystal Oscillator Output	X1	374	158	
Power Supply Ground	VSS	830	1008	
Crystal/Varactor Oscillator Input	X2	817	158	
Buffer Output	OUT	665	1015	

Note: Because the substrate of the die is internally connected to VDD, the die has to be connected to VDD or left floating. Please make sure that VDD is the first pad to be bonded. Pick-and-place and all component assembly are recommended to be performed in ESD protected area.

Note: Pad coordinates measured from the left bottom corner of the chip to the center of the pads. The coordinates may vary depending on sawing width and location, however, distances between pads are accurate.

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Min	Max	Unit	Note
Supply Voltage	V_{DD} - V_{SS}	-0.3	6.0	V	
Input Voltage	V _{IN}	V _{SS} -0.3	V _{DD} + 0.3	V	1)
Power Dissipation	P _{MAX}		100	mW	
Storage Temperature	T _{ST}	-40	120	°C	

Note: Not valid for programming pin PV

RECOMMENDED OPERATION CONDITIONS

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Supply Voltage	V _{DD}		2.5	2.8	5.5	V
Supply Current	I _{CC}	Vdd = 2.8 Volt		2.3		mA
Operable Temperature	T _C		-40		+85	°C
Storage Temperature	Ts	Relative humidity = 15%…70%	-5		+40	°C



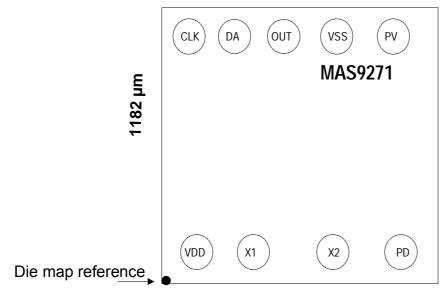
ELECTRICAL CHARACTERISTICS

(recommended operation conditions)

Parameter	Symbol	Min	Тур	Max	Unit	Note
Frequency Range	f _o	10.00		40.00	MHz	1)
Output Voltage (10 pF, Vdd 2.7V)	V _{out}		2.3		Vpp	
Output Voltage (10 pF, Vdd 5.0V)	V _{out}		4.5		Vpp	
Rise and Fall Time (10 - 50pF)				10	ns	
Output Symmetry			40-60		%	
Crystal Load	C _G	5.1		11.5	pF	2)
Startup Time	T _{START}		2		ms	
Negative Resistance in Maximum Load at 32 MHz	NegR	85			Ω	
Negative Resistance in Maximum Load at 40 MHz	NegR	40			Ω	
Tri State Output Buffer ON State OFF State	PD	0 1.6		0.55 VDD	V	

Note 1: Rs < 10 Ω crystal provides typically a maximum frequency of 40 MHz and Rs<30 Ω a maximum frequency of 32 MHz. With Rs = 50 Ω crystal the maximum frequency is typically 26 MHz. **Note 2:** Crystal Load is at minimum when all CDAC bits are 0s, and at maximum when all CDAC bits are 1s.

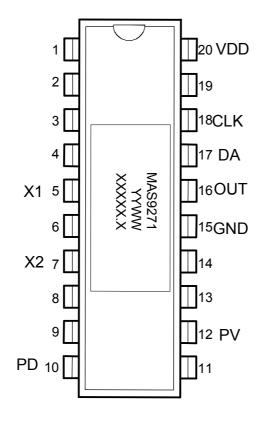
IC OUTLINES



1200 µm

Note 1: MAS9271 pads are round with 80 µm diameter at opening. **Note 2**: Pins PV, CLK and DA must not be connected in PXO module end-user application.





Top marking: YYWW = Year, Week XXXXX.X = Lot number



ORDERING INFORMATION

Product Code	Product	Package	Comments
MAS9271ATB1	IC FOR PXO	Tested wafers 480 µm	Die size 1200 x 1182 µm
MAS9271ATG1	IC FOR PXO	Tested wafers 215 µm	Die size 1200 x 1182 µm

Please contact Micro Analog Systems Oy for other wafer thickness options.

LOCAL DISTRIBUTOR

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